

DESCRIPTION

The LX1004 Micropower Voltage References are two terminal bandgap reference diodes designed and optimized for accurate low power operation in portable and other power sensitive systems. Operating currents are guaranteed from as low as 10µA up to 20mA giving designers a great deal of flexibility in optimizing power consumption, noise and ultimate application performance. The LX1004 is available in fixed 1.2V and 2.5V reference values.

Process and circuit design optimization provide for high accuracy with initial tolerance values of ±4mV and ±20mV, respectively. Complementing their initial accuracy, the bandgap reference is temperature compensated to deliver 20ppm performance over the 0° to 70°C operating temperature range.

The LX1004 from LInfinity is a pin for-pin replacement for the LT1004 and LM385 families of voltage references.

KEY FEATURES

- Guaranteed ±4mV Initial Accuracy LX1004-1.2
- Guaranteed ±20mV Initial Accuracy LX1004-2.5
- Guaranteed 10µA Operating Current
- Guaranteed Temperature Performance
- Operates Up to 20mA
- Very Low Dynamic Impedance

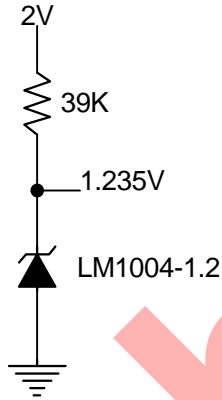
APPLICATIONS

- Portable Meter References
- Portable Test Instruments
- Battery Operated Systems
- Current Loop Instrumentation

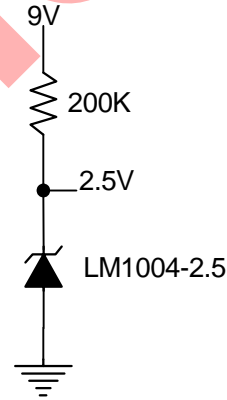
IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

PRODUCT HIGHLIGHT

MICROPOWER REFERENCE FROM 2 CELL BATTERY



MICROPOWER REFERENCE FROM 9V BATTERY



PACKAGE ORDER INFO

T _A (°C)	Reference Voltage	Initial Tolerance	DM	Plastic SOIC 8-Pin	LP	Plastic TO-92 3-Pin
			RoHS Compliant / Pb-free Transition DC: 0440		RoHS Compliant / Pb-free Transition DC: 0509	
0 to 70	1.2V	±4mV	LX1004CDM-1.2		LX1004CLP-1.2	
	2.5V	±20mA	LX1004CDM-2.5		LX1004CLP-2.5	

Note: Available in Tape & Reel. Append the letters "TR" to the part number (i.e. LX1004CDM-2.5-TR).

ABSOLUTE MAXIMUM RATINGS (Note 1)

Reverse Breakdown Current	30mA
Forward Current	10mA
Operating Temperature Range	0°C to 70°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (soldering, 10 seconds)	300°C
Pb-free / RoHS Peak Package Solder Reflow Temp (40 second max. exposure)	260°C (+0, -5)

Note 1. Values beyond which damage may occur. All voltages are specified with respect to ground, and all currents are positive into the specified terminal

THERMAL DATA

DM PACKAGE:

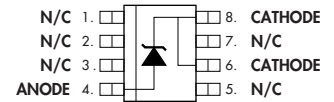
THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	165°C/W
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LP PACKAGE:

THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	165°C/W
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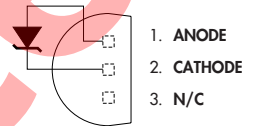
The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

PACKAGE PIN OUTS



DM PACKAGE (Top View)

100% Pb-free / RoHS Matte Tin Lead Finish



LP PACKAGE (Top View)

Obsolète

1.2V & 2.5V MICROPOWER VOLTAGE REFERENCES

PRODUCTION DATA SHEET

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, these specifications apply to $T_A = 25^\circ\text{C}$ for LX1004C. Typ. number represents $T_A = 25^\circ\text{C}$ value.)

LX1004 - 1.2

Parameter	Symbol	Test Conditions	LX1004 - 1.2			Units
			Min.	Typ.	Max.	
Reverse Breakdown Voltage	V_Z	$I_R = 100\mu\text{A}, T_A = 25^\circ\text{C}$	1.231	1.235	1.239	V
		$0^\circ \leq T_A \leq 70^\circ\text{C}$	1.225	1.235	1.245	V
Average Temperature Coefficient	$\frac{\Delta V_Z}{\Delta \text{Temp}}$	$I_{\text{MIN}} \leq I_R \leq 20\text{mA}$		20		ppm/ $^\circ\text{C}$
Minimum Operating Current	I_{MIN}	$0^\circ \leq T_A \leq 70^\circ\text{C}$		8	10	μA
Reverse Breakdown Voltage Change with Current	$\frac{\Delta V_Z}{\Delta I_R}$	$I_{\text{MIN}} \leq I_R \leq 1\text{mA}, T_A = 25^\circ\text{C}$			1	mV
		$I_{\text{MIN}} \leq I_R \leq 1\text{mA}, 0^\circ \leq T_A \leq 70^\circ\text{C}$			1.5	mV
		$1\text{mA} \leq I_R \leq 20\text{mA}, T_A = 25^\circ\text{C}$			10	mV
Reverse Dynamic Impedance	r_z	$I_R = 100\mu\text{A}, T_A = 25^\circ\text{C}$		0.2	0.6	Ω
		$I_R = 100\mu\text{A}, 0^\circ \leq T_A \leq 70^\circ\text{C}$			1.5	Ω
Wide Band Noise (RMS)	e_n	$I_R = 100\mu\text{A}; 10\text{Hz} \leq f \leq 10\text{kHz}$		60		μV
Long Term Stability	$\frac{\Delta V_Z}{\Delta \text{Time}}$	$I_R = 100\mu\text{A}; T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$		20		ppm/kHr

LX1004 - 2.5

Parameter	Symbol	Test Conditions	LX1004 - 2.5			Units
			Min.	Typ.	Max.	
Reverse Breakdown Voltage	V_Z	$I_R = 100\mu\text{A}, T_A = 25^\circ\text{C}$	2.480	2.500	2.520	V
		$0^\circ \leq T_A \leq 70^\circ\text{C}$	2.470		2.530	V
Average Temperature Coefficient	$\frac{\Delta V_Z}{\Delta \text{Temp}}$	$I_{\text{MIN}} \leq I_R \leq 20\text{mA}$		20		ppm/ $^\circ\text{C}$
Minimum Operating Current	I_{MIN}	$0^\circ \leq T_A \leq 70^\circ\text{C}$		12	20	μA
Reverse Breakdown Voltage Change with Current	$\frac{\Delta V_Z}{\Delta I_R}$	$I_{\text{MIN}} \leq I_R \leq 1\text{mA}, T_A = 25^\circ\text{C}$			1	mV
		$I_{\text{MIN}} \leq I_R \leq 1\text{mA}, 0^\circ \leq T_A \leq 70^\circ\text{C}$			1.5	mV
		$1\text{mA} \leq I_R \leq 20\text{mA}, T_A = 25^\circ\text{C}$			10	mV
Reverse Dynamic Impedance	r_z	$I_R = 100\mu\text{A}, T_A = 25^\circ\text{C}$		0.2	0.6	Ω
		$I_R = 100\mu\text{A}, 0^\circ \leq T_A \leq 70^\circ\text{C}$			1.5	Ω
Wide Band Noise (RMS)	e_n	$I_R = 100\mu\text{A}; 10\text{Hz} \leq f \leq 10\text{kHz}$		120		μV
Long Term Stability	$\frac{\Delta V_Z}{\Delta \text{Time}}$	$I_R = 100\mu\text{A}; T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$		20		ppm/kHr

GRAPH / CURVE INDEX

Characteristic Curves — LX1004-1.2V

FIGURE

- TEMPERATURE DRIFT
- REVERSE CHARACTERISTICS
- REVERSE VOLTAGE CHANGE
- FORWARD CHARACTERISTICS
- REVERSE DYNAMIC IMPEDANCE
- NOISE VOLTAGE
- RESPONSE TIME

Characteristic Curves — LX1004-2.5V

FIGURE

- RESPONSE TIME
- REVERSE CHARACTERISTICS
- FORWARD CHARACTERISTICS
- TEMPERATURE DRIFT
- NOISE VOLTAGE
- REVERSE DYNAMIC IMPEDANCE

CHARACTERISTIC CURVES — LX1004-1.2V

FIGURE 1. — TEMPERATURE DRIFT

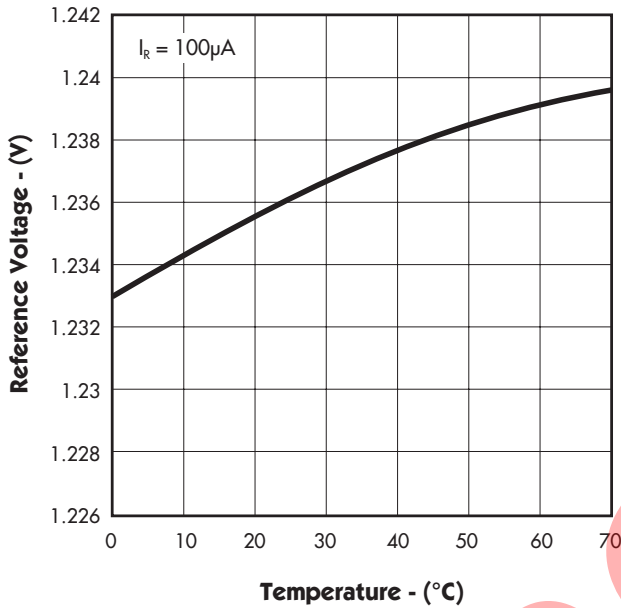


FIGURE 2. — REVERSE CHARACTERISTICS

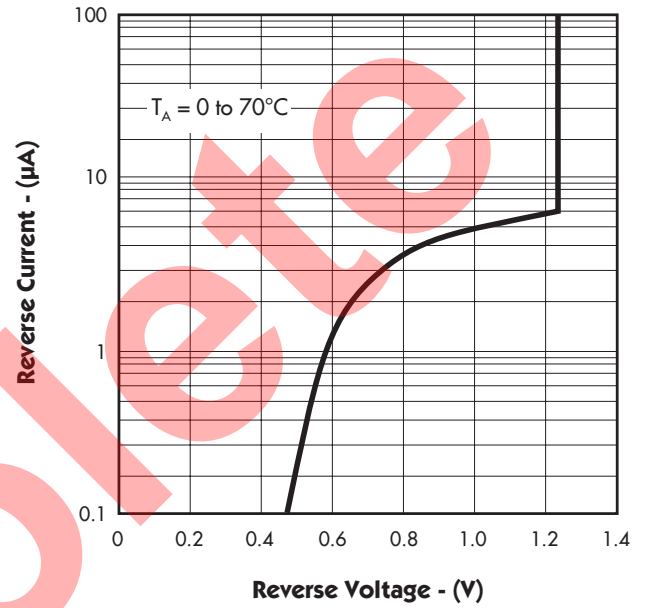


FIGURE 3. — REVERSE VOLTAGE CHANGE

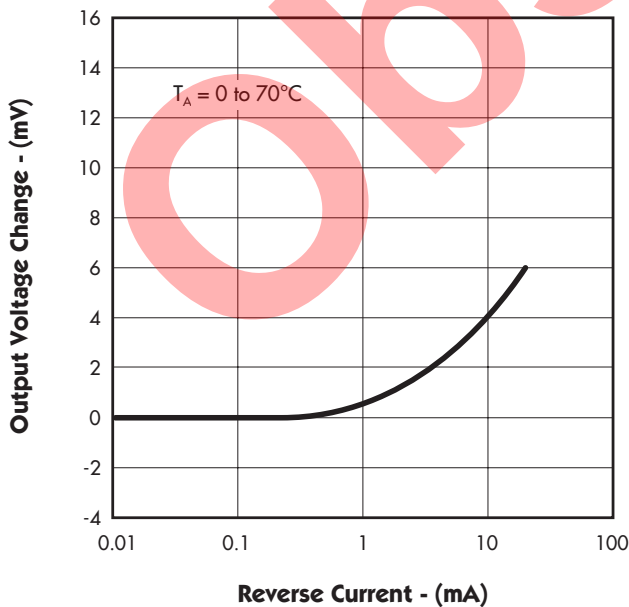
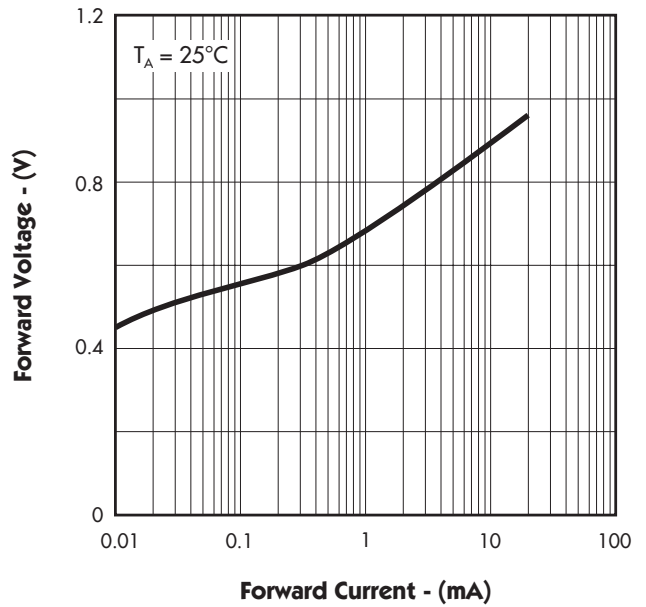


FIGURE 4. — FORWARD CHARACTERISTICS



1.2V & 2.5V MICROPOWER VOLTAGE REFERENCES

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CHARACTERISTIC CURVES — LX1004-1.2V

FIGURE 5. — REVERSE DYNAMIC IMPEDANCE

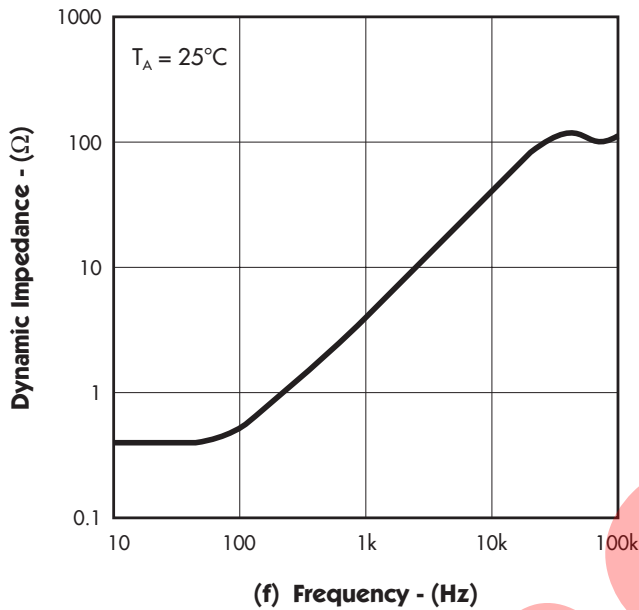


FIGURE 6. — NOISE VOLTAGE

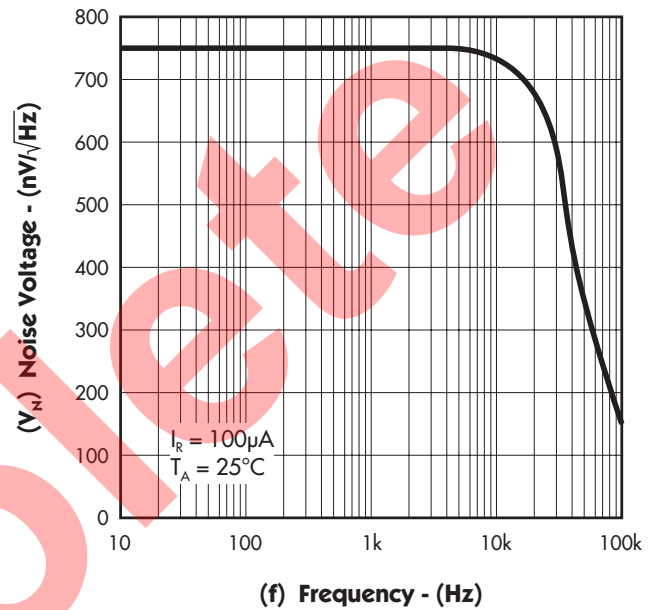
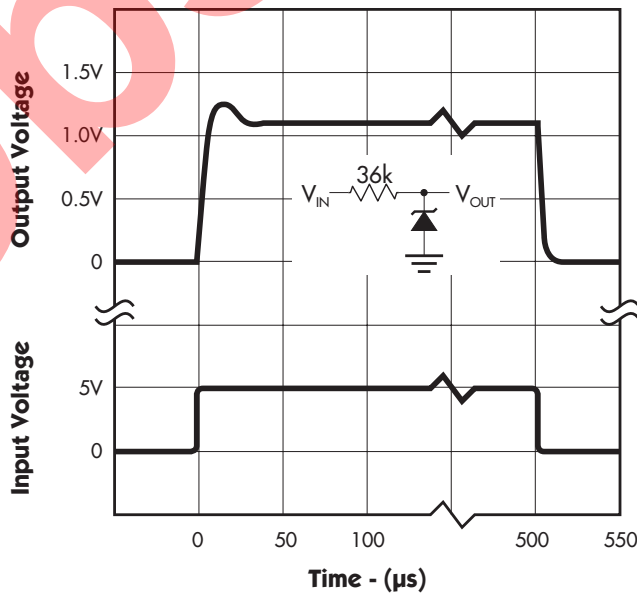


FIGURE 7. — RESPONSE TIME



CHARACTERISTIC CURVES — LX1004-2.5V

FIGURE 8. — RESPONSE TIME

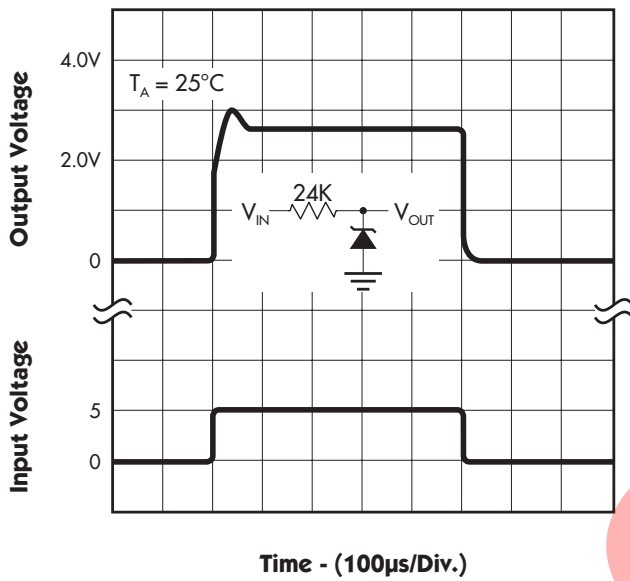


FIGURE 9. — REVERSE CHARACTERISTICS

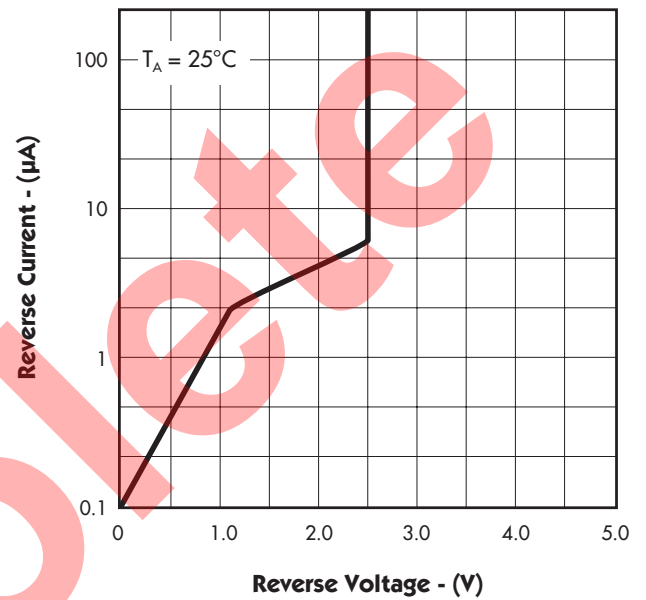


FIGURE 10. — FORWARD CHARACTERISTICS

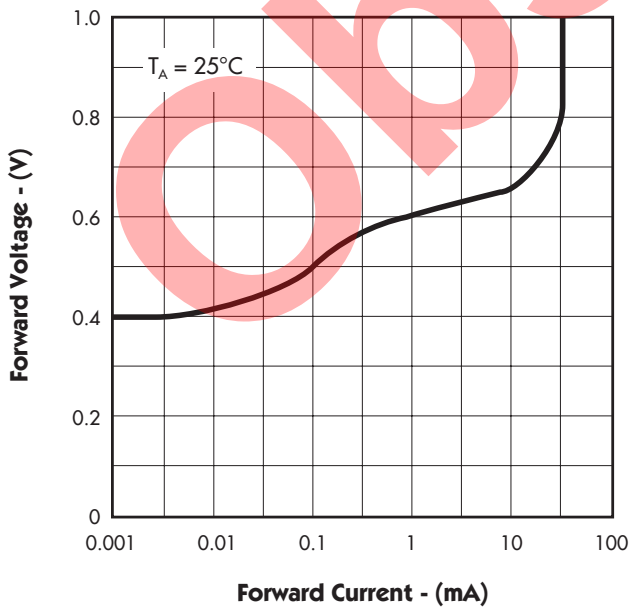
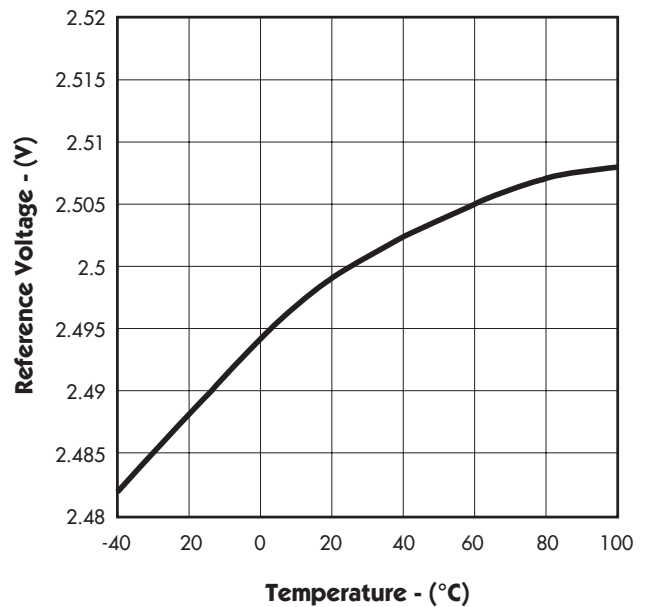


FIGURE 11. — TEMPERATURE DRIFT



1.2V & 2.5V MICROPOWER VOLTAGE REFERENCES

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CHARACTERISTIC CURVES — LX1004-2.5V

FIGURE 12. — NOISE VOLTAGE

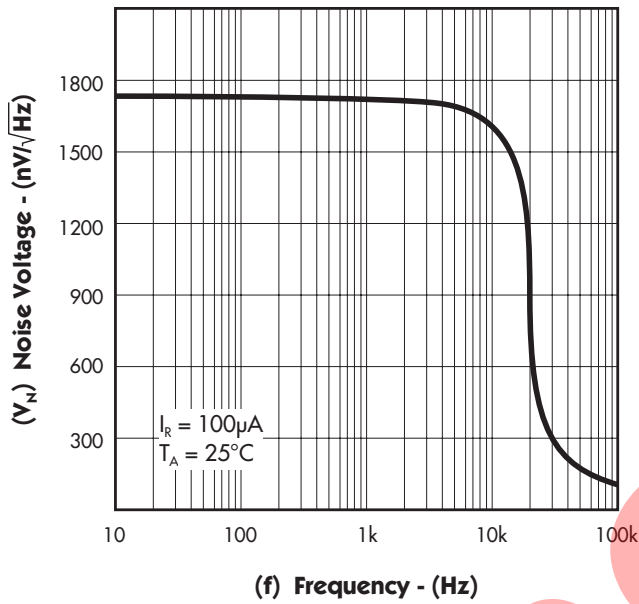


FIGURE 13. — REVERSE DYNAMIC IMPEDANCE

